

Surface Mount Glass Passivated Rectifier

Features

- Glass passivated chip junction
- Built in strain relief
- High current capability
- Low forward voltage drop
- Fast switching speed for high efficiency
- High temperature Soldering guaranteed: 260 ℃/ 10 seconds at terminals
- RoHS and REACH compliance

Mechanical Data





DO-214AA (SMB)

RoHS COMPLIANT

Case:	JEDEC DO-214AA (SMB), transfer molded plastic					
Ероху:	Meets UL 94V-0 flammability rating					
Terminals:	Solder plated, solderable per MIL-STD 750, Method 2026					
Polarity:	Cathode indicated by color band					
Mounting position:	Any					
Weight:	0.003 ounce, 0.093 gram					

Maximum Ratings (*T* Ambient=25°C unless noted otherwise)

	0									
Symbol	Description	S3AB	S3BB	S3DB	S3GB	S3JB	S3KB	S3MB	Unit	Conditions
VRRM	Max Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	v	
VRMS	Max RMS Voltage	35	70	140	280	420	560	700	v	
VDC	Max DC Blocking Voltage	50	100	200	400	600	800	1000	v	
I(AV)	Max Average Forward Rectified Current at Ambient Temperature	3.0							А	TL=75℃ (note 2)
IFSM	Peak Forward Surge Current	100							А	8.3ms single half sine- wave (JEDEC)
trr	Maximum Reverse Recovery Time	2.5							μS	IF=0.5A, IR=1.0A, IRR=0.25A
TJ,TSTG	Operating and Storage Temperature Range	-55 to +150						Ċ		

Electrical Characteristics (T Ambient=25°C unless noted otherwise)

Symbol	Description	S3AB	S3BB	S3DB	S3GB	S3JB	S3KB	S3MB	Unit	Conditions
VF	Max Instantaneous Forward Voltage				1.2				v	IF(AV)= 3.0A
IR Max DC Reverse Curren Rated DC Blocking Volta	Max DC Reverse Current at				5.0					TA=25 ℃
	Rated DC Blocking Voltage				250				μA	TA=125 ℃
c	Typical Junction Capacitance				60				pF	At 1MHz, reversed voltage of 4V
Rθ-JA	47									
RÐ-JL	Typical Thermal Resistance				13				°C/W	Note 2

Note:

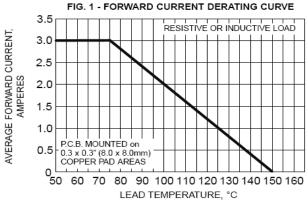
1. Single phase, half wave, 60Hz, resistive or inductive load. Derate current by 20% for capacitive load

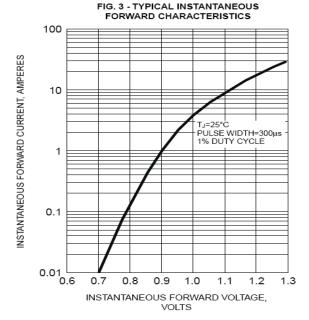
2. Thermal Resistance from junction to ambient and from junction to lead mounted on PCB with 0.3" x 0.3" (8.0mm x 8.0mm) copper pad areas.



S3AB ~ S3MB

Typical Characteristics Curves





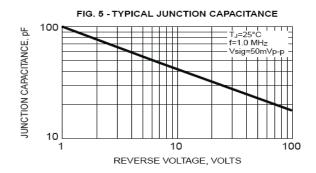


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT 200 TL=75°C 8.3ms SINGLE HALF SINE-WAVE (JEDEC Method) PEAK FORWARD SURGE CURRENT, AMPERES ||100 10 10 100 1 NUMBER OF CYCLES AT 60 Hz

FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

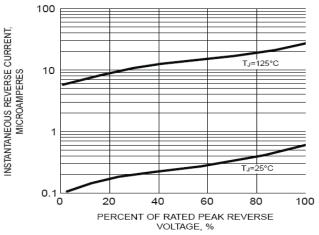


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE 100 MOUNTED ON 0.20 x 0.27" (5 x 7mm COPPER PAD AREAS 10 1 ₩ 0.1 0.01 0.1 1 10 100

t, PULSE DURATION, sec

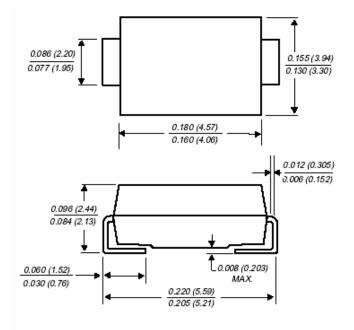
TRANSIENT THERMAL IMPEDANCE (°C/W)

Rev. 0 2010-07-15



S3AB ~ S3MB

Dimensions in inch (mm)



Dimensions in inches and (millimeters)

DO-214AA(SMB)

Contact us:

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